

Datasheet

Complementary power Darlington transistors



Features

- Good h_{FE} linearity
- High f_T frequency
- Monolithic Darlington configuration with integrated antiparallel collector-emitter diode

Application

- Audio amplifiers
- Linear and switching industrial equipment



C (2, TAB)

R₁ typ. = 10 kΩ

R₂ typ. = 150 Ω



Description

These devices are manufactured in planar technology with "base island" layout and monolithic Darlington configuration.







Electrical ratings

Table 1. Absolute maximum ratings

	Parameter		Va		
Symbol		NPN	BDX53B	BDX53C	Unit
		PNP		BDX54C	
V _{CBO}	Collector-base voltage (I _E = 0 A)		80	100	V
V _{CEO}	Collector-emitter voltage (I _B = 0 A)		80	100	V
V _{EBO}	Collector-base voltage (I _C = 0 A)		5		V
I _C	Collector current		8		Α
I _{CM}	Collector peak current		12		Α
I _B	Base current		0.2		Α
P _{TOT}	Total power dissipation at T _C = 25 °C		60		W
T _{stg}	Storage temperature range		-65 to 150		°C
TJ	Maximum operating junction temperature		150		°C

Note: For PNP types voltage and current values are negative.

Table 2. Thermal data

Symbol	Parameter	Value	Unit
R _{thJC}	Thermal resistance, junction-to-case	2.08	°C/W

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2 Electrical characteristics

 T_C = 25 °C unless otherwise specified.

Table 3. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current	V_{CB} = 80 V, I_E = 0 A for BDX53B	-	-	0.2	mA
		V _{CB} = 100 V, I _E = 0 A for BDX53C, BDX54C	-	-	0.2	mA
loro	Collector cut-off current	V_{CE} = 40 V, I_B = 0 A for BDX53B	-	-	0.5	mA
I _{CEO}		V_{CE} = 50 V, I_B = 0 A for BDX53C, BDX54C	-	-	0.5	mA
I _{EBO}	Emitter cut-off current	V _{EB} = 5 V, I _C = 0 A	-	-	2	mA
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage	I _C = 100 mA, I _B = 0 A for BDX53B	80	-	-	V
		I _C = 100 mA, I _B = 0 A for BDX53C, BDX54C	100	-	-	V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	I _C = 3 A, I _B = 12 mA	-	-	2	V
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	I _C = 3 A, I _B = 12 mA	-	-	2.5	V
h _{FE} ⁽¹⁾	DC current gain	I _C = 3 A, V _{CE} = 3 V	750	-	-	-
V _F ⁽¹⁾	Diada fanuard valtaga	I _F = 3 A	-	1.8	2.5	V
	Diode forward voltage	I _F = 8 A	-	2.5	-	V

^{1.} Pulse test: pulse duration = 300 μ s, duty cycle 1.5 %.

Note: For PNP types voltage and current values are negative.

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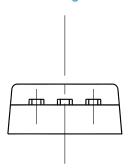


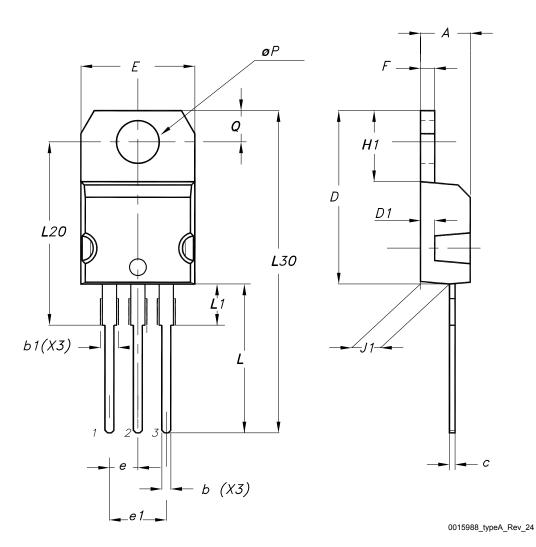
3 Package information

To meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions, and product status are available at: www.st.com. ECOPACK is an ST trademark.

3.1 TO-220 type A package information

Figure 1. TO-220 type A package outline





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Table 4. TO-220 type A package mechanical data

Dim.		mm	
DIM.	Min.	Тур.	Max.
A	4.40		4.60
b	0.61		0.88
b1	1.14		1.55
С	0.48		0.70
D	15.25		15.75
D1		1.27	
E	10.00		10.40
е	2.40		2.70
e1	4.95		5.15
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13.00		14.00
L1	3.50		3.93
L20		16.40	
L30		28.90	
øΡ	3.75		3.85
Q	2.65		2.95
Slug flatness		0.03	0.10

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4 Ordering information

Table 5. Order codes

Order codes	Marking	Polarity	Package	Packing
BDX53B	BDX53B	NPN		
BDX53C	BDX53C	NPN	TO-220	Tube
BDX54C	BDX54C	PNP		

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Revision history

Table 6. Document revision history

Date	Revision	Changes
23-Oct-2007	4	Technology change from epibase to planar (PCN APMPWR/07/2417 and APM-PWR/07/2615)
		Removed order code BDX54B.
17-Jul-2025	5	Updated Table 1. Absolute maximum ratings and Section 3: Package information.
		Minor text changes.

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